## NSN 5961-01-338-2179

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-338-2179 **Inclosure Material:** Metal **Overall Length:** Between 0.245 inches and 0.255 inches **Terminal Length:** 0.250 inches **Overall Height:** 0.070 inches **Overall Width:** 0.750 inches **Function For Which Designed:** Switching **End Application:** Test system, avionics an/usm-24 (v) Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-91 **Component Name And Quantity:** 8 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 30.0 breakdown voltage, collector-to-emitter, base open all transistor **Current Rating Per Characteristic:** 10.00 nanoamperes zero-gate-voltage source current minor all transistor **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Terminal Type And Quantity:** 10 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

A110a0